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HFA200FA120P

Vishay Semiconductors

HEXFRED[®] Ultrafast Soft Recovery Diode, 200 A



1200 V

2.7 V

150 ns

100 A at 69 °C

PRODUCT SUMMARY

 V_{R}

V_F (typical)

t_{rr} (typical)

 $I_{F(DC)}$ at T_C

FEATURES	5
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- Fast recovery time characteristic
- Electrically isolated base plate
- Large creepage distance between terminal
- Simplified mechanical designs, rapid assembly
- UL approved file E78996
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level

DESCRIPTION/APPLICATIONS

The dual diode series configuration (HFA200FA120P) is used for output rectification or freewheeling/clamping operation and high voltage application.

The semiconductor in the SOT-227 package is isolated from the copper base plate, allowing for common heatsinks and compact assemblies to be built.

These modules are intended for general applications such as HV power supplies, electronic welders, motor control and inverters.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Cathode to anode voltage	V _R		1200	V	
Continuous forward current	IF	T _C = 69 °C	100		
Single pulse forward current	I _{FSM}	T _J = 25 °C	900	A	
Maximum repetitive forward current	I _{FRM}	Rated $V_{R,}$ square wave, 20 kHz, T_{C} = 60 °C	150		
Maximum power dissipation	Р	T _C = 25 °C	416	w	
Maximum power dissipation	PD	T _C = 100 °C	166		
RMS isolation voltage	V _{ISOL}	Any terminal to case, t = 1 minute	2500	V	
Operating junction and storage temperature range	T _J , T _{Stg}		- 55 to 150	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA	1200	-	-	
Forward voltage	V _{FM}	I _F = 100 A	-	2.68	3.6	V
		I _F = 200 A	-	3.37	4.7	
		I _F = 100 A, T _J = 150 °C	-	2.7	2.9	1
Reverse leakage current		$V_{R} = V_{R}$ rated	-	10	75	μA
	I _{RM}	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	2	-	mA



COMPLIANT

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time t _{rr}		T _J = 25 °C	I _F = 50 A dI _F /dt = - 200 A/μs V _R = 200 V	-	150	-	ns
	۲rr	T _J = 125 °C		-	237	-	
Peak recovery current	I _{RRM}	T _J = 25 °C		-	14	-	A
		T _J = 125 °C		-	21	-	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	1050	-	nC
		T _J = 125 °C		-	2430	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Junction to case, single leg conducting	Б		-	-	0.3	
Junction to case, both legs conducting	R _{thJC}		-	-	0.15	°C/W
Case to heatsink	R _{thCS}	Flat, greased and surface	-	0.05	-	
Weight			-	30	-	g
Mounting torque			-	1.3	-	Nm

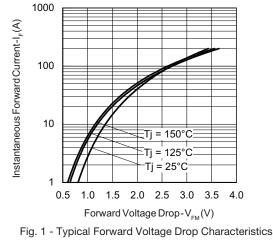
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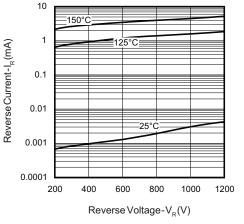


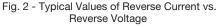
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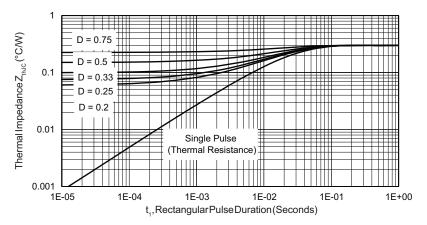


Fig. 3 - Maximum Thermal Impedance Z_{thJC} Characteristics

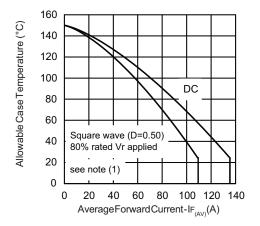


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

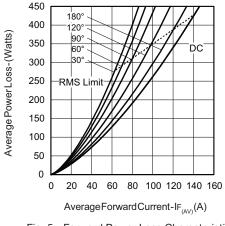


Fig. 5 - Forward Power Loss Characteristics

For technical questions within your region, please contact one of the following: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u>

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ISHA

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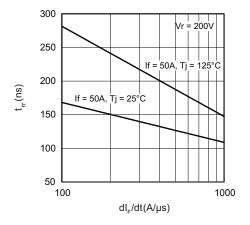


Fig. 6 - Typical Reverse Recovery Time vs. dl_F/dt

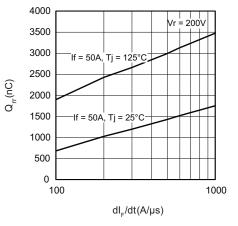


Fig. 7 - Typical Stored Charge vs. dl_F/dt

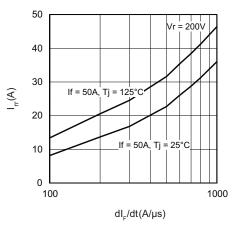


Fig. 8 - Typical Peak Recovery Current vs. dl_F/dt

Note

- (1) Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{th,JC};$ $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 5); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 D); I_R at V_{R1} = Rated V_R$

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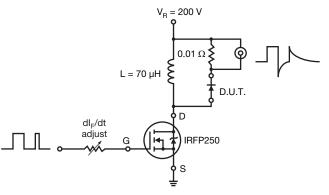


Fig. 9 - Reverse Recovery Parameter Test Circuit

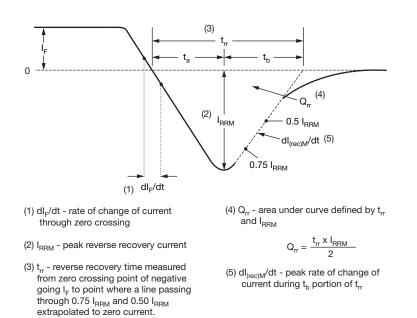


Fig. 10 - Reverse Recovery Waveform and Definitions

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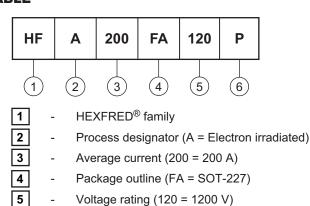
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ORDERING INFORMATION TABLE

Device code

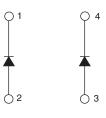


Average current (200 = 200 A)

- Package outline (FA = SOT-227)
- Voltage rating (120 = 1200 V)
- P = Lead (Pb)-free

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CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?95036</u>						
Packaging information	www.vishay.com/doc?95037					

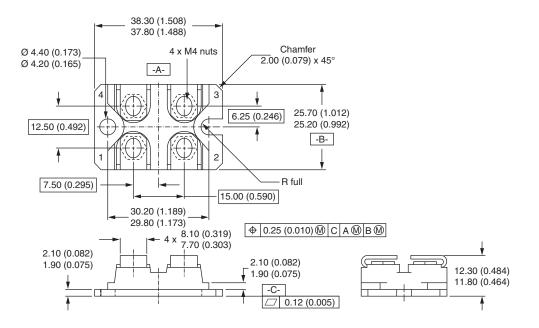


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SOT-227

DIMENSIONS in millimeters (inches)



Notes

- Dimensioning and tolerancing per ANSI Y14.5M-1982
- Controlling dimension: millimeter



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